



DEVICE NUMBER : DPD-042-067  
ECN : \_\_\_\_\_

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## 5mm Silicon PIN Photodiode

MODEL NO : PD423-3C/H22/L1

### ■ Features :

- Fast response time
- High photo sensitivity
- Small junction capacitance

### ■ Description :

PD423-3C/H22/L1 is a high speed and high sensitive PIN photodiode in a standard 5Φ plastic package. The device is spectrally matched to infrared emitting diode.

### ■ Applications :

- High speed photo detector
- Camera
- Optoelectronic switch
- VCRs ,Video camera
- Floppy disk drive

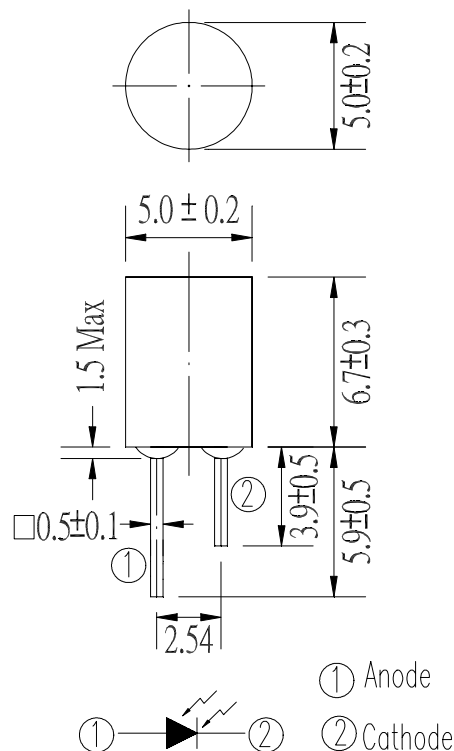
| PART NO. | CHIP     | LENS COLOR  |
|----------|----------|-------------|
|          | MATERIAL |             |
| PD       | Silicon  | Water Clear |



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### ■ Package Dimensions :



### ■ Notes :

- 1.All dimensions are in millimeter.
- 2.Protruded resin under flange 1.5 mm Max.
- 3.Lead spacing is measured where the lead emerge from the package.
- 4.Lens color : Water Clear.
- 5.Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.
- 6.These specification sheets include materials protected under copyright of EVERLIGHT corporation . Please don't reproduce or cause anyone to reproduce them without EVERLIGHT's consent.
- 7.When using this product , please observe the absolute maximum ratings and the instructions for use outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.



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### ■ Absolute Maximum Ratings at T<sub>A</sub> = 25°C

| Parameter                  | Symbol           | Rating     | Unit | Notice |
|----------------------------|------------------|------------|------|--------|
| Reverse Voltage            | V <sub>R</sub>   | 32         | V    |        |
| Power Dissipation          | P <sub>d</sub>   | 150        | mW   |        |
| Lead Soldering Temperature | T <sub>sol</sub> | 260        | °C   |        |
| Operating Temperature      | T <sub>opr</sub> | -40 ~ +85  | °C   |        |
| Storage Temperature        | T <sub>stg</sub> | -55 ~ +100 | °C   |        |

### ■ Electronic Optical Characteristics :

| Parameter                      | Symbol                         | Min. | Typ.     | Max. | Unit | Condition                                                            |
|--------------------------------|--------------------------------|------|----------|------|------|----------------------------------------------------------------------|
| Rang of Spectral Bandwidth     | $\lambda_{0.5}$                | ---- | 400-1200 | ---- | nm   | -----                                                                |
| Wavelength of Peak Sensitivity | $\lambda_p$                    | ---- | 980      | ---- | nm   | -----                                                                |
| Open-Circuit Voltage           | V <sub>oc</sub>                | ---- | 300      | ---- | mV   | Ee=0.5m W/c m <sup>2</sup><br>$\lambda_p$ =940nm                     |
| Short- Circuit Current         | I <sub>sc</sub>                | 1.0  | 2.0      | ---- | μA   |                                                                      |
| Reverse Light Current          | I <sub>L</sub>                 | ---- | 20       | ---- | μA   | Ee=5m W/c m <sup>2</sup><br>$\lambda_p$ =940nm<br>V <sub>R</sub> =5V |
| Dark Current                   | I <sub>d</sub>                 | ---- | ----     | 10   | nA   | Ee=0m W/c m <sup>2</sup><br>V <sub>R</sub> =10V                      |
| Reverse Breakdown Voltage      | BV <sub>R</sub>                | 32   | 170      | ---- | V    | Ee=0m W/c m <sup>2</sup><br>I <sub>R</sub> =100μA                    |
| Total Capacitance              | C <sub>t</sub>                 | ---- | 6        | ---- | pF   | Ee=0m W/c m <sup>2</sup><br>V <sub>R</sub> =5V, f=1MHz               |
| Rise/Fall Time                 | t <sub>r</sub> /t <sub>f</sub> | ---- | 10/10    | ---- | nS   | V <sub>R</sub> =10V<br>R <sub>L</sub> =1KΩ                           |



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### ■ Typical Electrical/Optical/Characteristics Curves

Fig. 1 Power Dissipation vs. Ambient Temperature

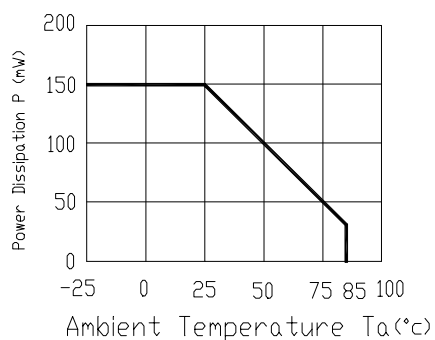


Fig. 2 Spectral Sensitivity

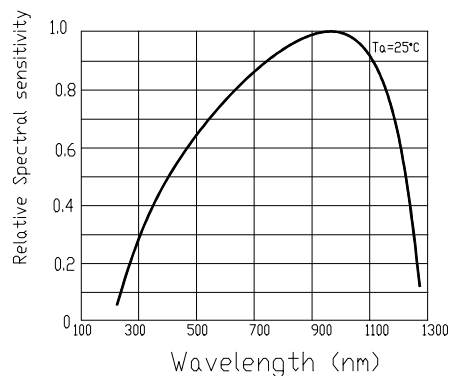


Fig. 3 Dark Current vs. Ambient Temperature

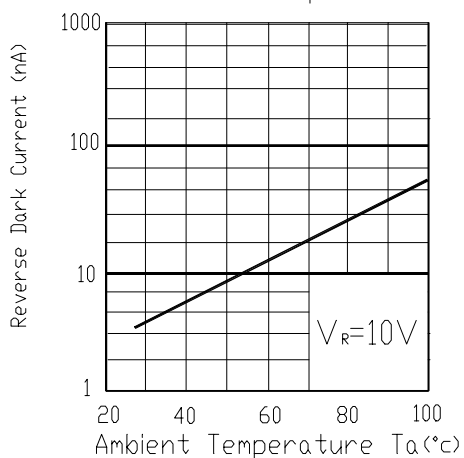


Fig. 4 Reverse Light Current vs.  $E_e$

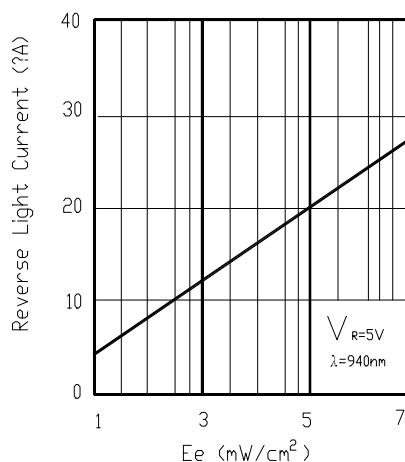


Fig. 5 Terminal Capacitance vs. Reverse Voltage

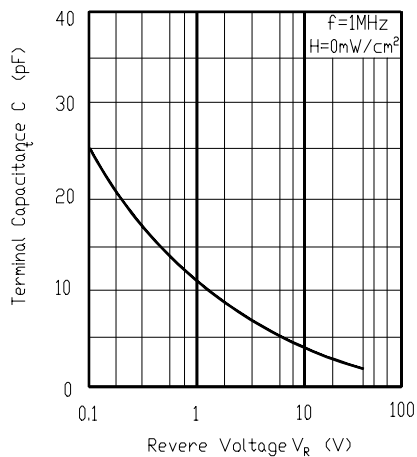
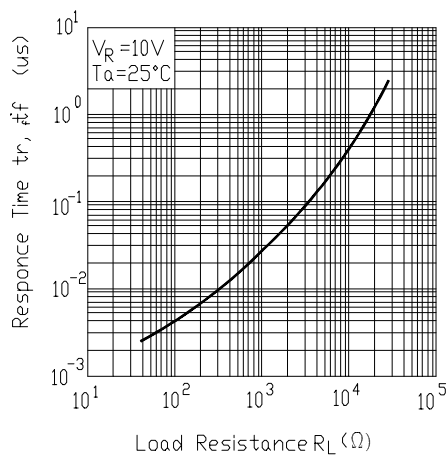


Fig. 6 Response Time vs. Load Resistance





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### ■ Reliability Test Item And Condition

The reliability of products shall be satisfied with items listed below.

Confidence level:90%

LTPD:10%

| NO. | Item                             | Test Conditions                                             | Test Hours/<br>Cycle | Sample<br>Size | Failure<br>Judgement<br>Criteria                                    | Ac/Re |
|-----|----------------------------------|-------------------------------------------------------------|----------------------|----------------|---------------------------------------------------------------------|-------|
| 1   | Solder Heat                      | TEMP : 260℃ ± 5 ℃                                           | 5 sec                | 22 PCs         | $I_L \leq L_x \times 0.8$<br><br>L :Lower<br>specification<br>limit | 0/1   |
| 2   | Temperature Cycle                | H : +85℃    30 min<br>↑<br>5 min<br>↓<br>L : -55℃    30 min | 50 cycle             | 22 PCs         |                                                                     | 0/1   |
| 3   | Thermal Shock                    | H : +100℃    5 min<br>↑<br>10 sec<br>↓<br>L : -10℃    5 min | 50 cycle             | 22 PCs         |                                                                     | 0/1   |
| 4   | High Temperature Storage         | TEMP. : +100℃                                               | 1000 hrs             | 22 PCs         |                                                                     | 0/1   |
| 5   | Low Temperature Storage          | TEMP. : -55℃                                                | 1000 hrs             | 22 PCs         |                                                                     | 0/1   |
| 6   | DC Operating Life                | V <sub>R</sub> =5V                                          | 1000 hrs             | 22 PCs         |                                                                     | 0/1   |
| 7   | High Temperature / High Humidity | 85℃ / 85% R.H.                                              | 1000 hrs             | 22 PCs         |                                                                     | 0/1   |



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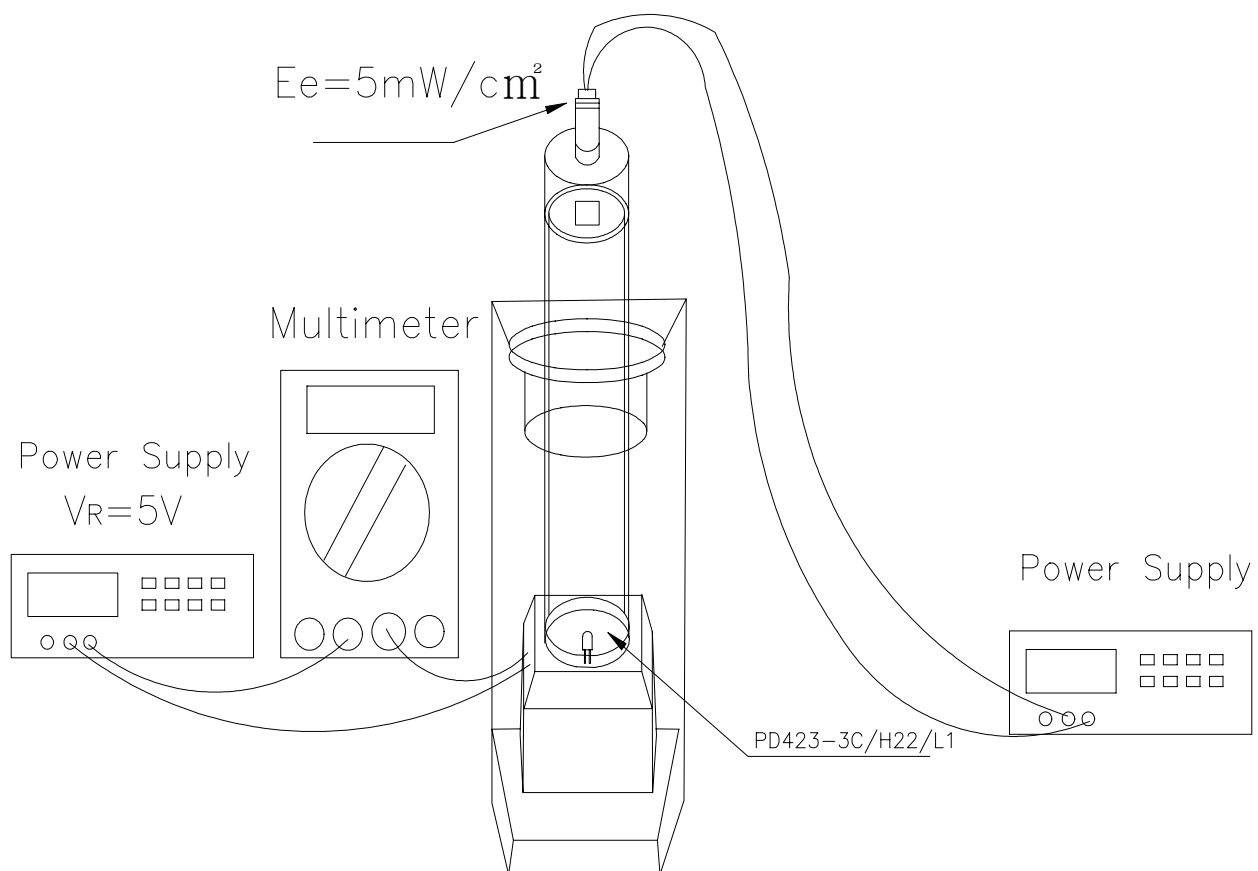
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### ■ Test Method For Reverse Light Current

Condition:  $E_e=5\text{mW}/\text{cm}^2$ ,  $V_R=5\text{V}$

Test Item: Reverse Light Current)

Unit :  $\mu\text{A}$





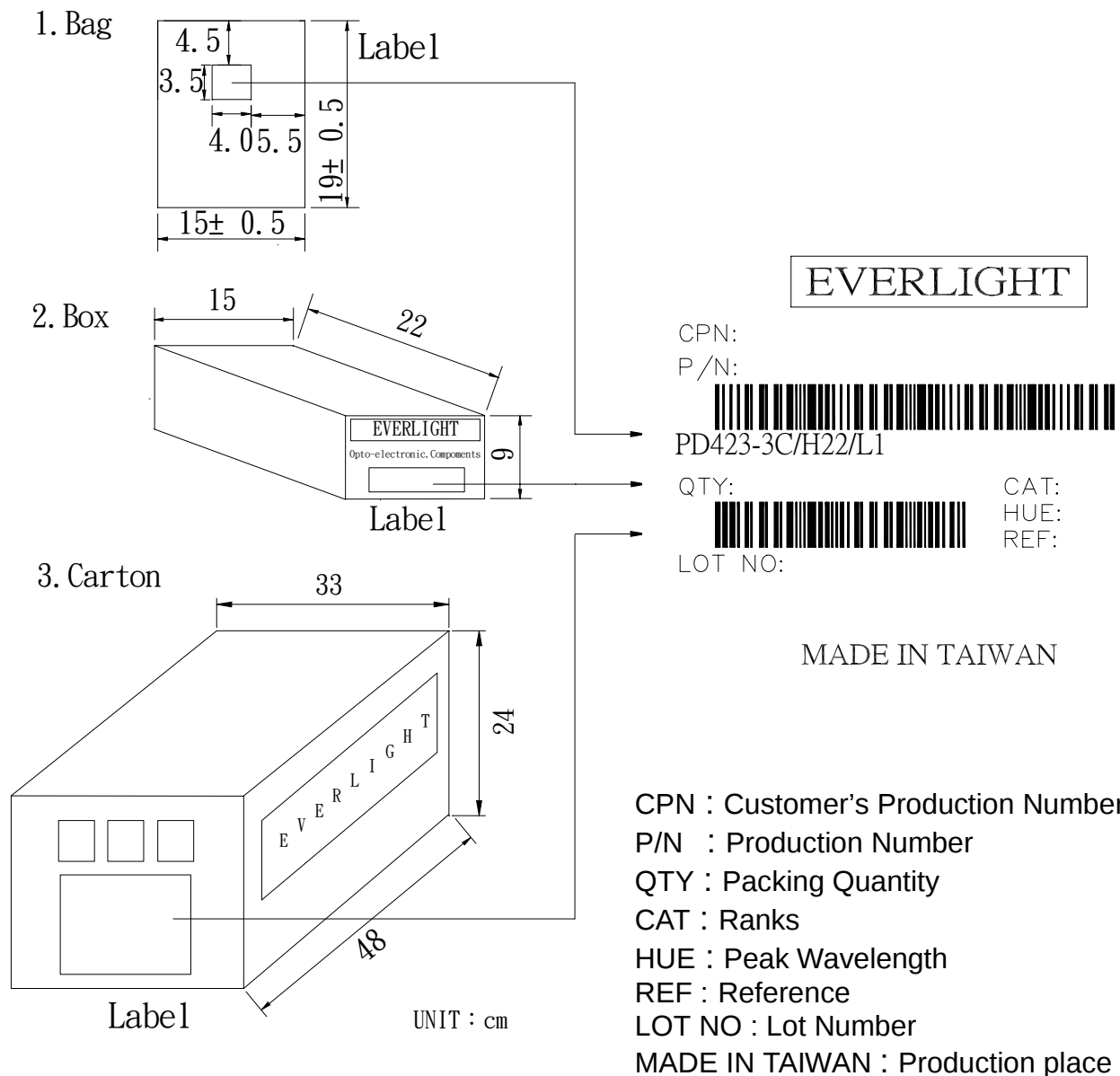
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### ■ Packing Specifications



### ■ Packing Quantity Specification

1. 500 Pcs/1Bag , 6 Bags/1Box
2. 10 Boxes/1Carton